

4K (512 x 8) CMOS EEPROM

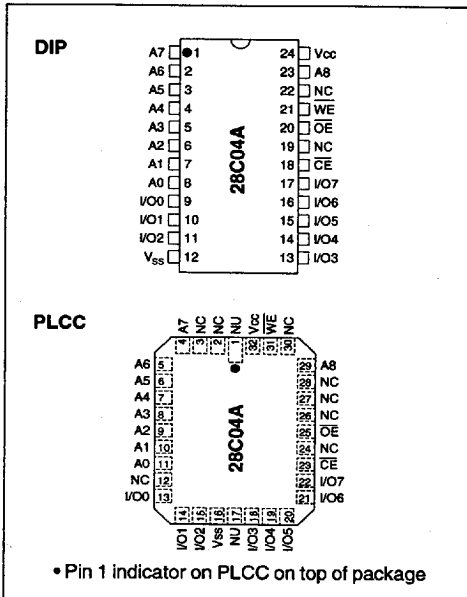
FEATURES

- Fast Read Access Time—150 ns
- CMOS Technology for Low Power Dissipation
 - 30 mA Active
 - 100 μ A Standby
- Fast Byte Write Time—200 μ s or 1 ms
- Data Retention >10 years
- Endurance - Minimum 10^4 Erase/Write Cycles
 - Automatic Write Operation
 - Internal Control Timer
 - Auto-Clear Before Write Operation
 - On-Chip Address and Data Latches
- Data Polling
- Chip Clear Operation
- Enhanced Data Protection
 - Vcc Detector
 - Pulse Filter
 - Write Inhibit
- 5-Volt-Only Operation
- Organized 512x8 JEDEC standard pinout
 - 24-pin Dual-In-Line Package
 - 32-pin Chip Carrier (Leadless or Plastic)
- Available for Extended Temperature Ranges:
 - Commercial: 0°C to +70°C
 - Industrial: -40°C to +85°C

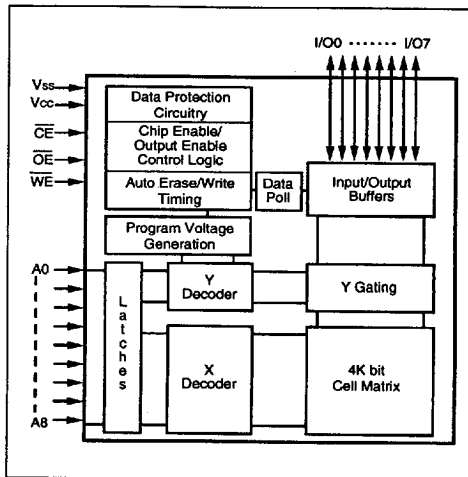
DESCRIPTION

The Microchip Technology Inc. 28C04A is a CMOS 4K non-volatile electrically Erasable and Programmable Read Only Memory (EEPROM). The 28C04A is accessed like a static RAM for the read or write cycles without the need of external components. During a "byte write", the address and data are latched internally, freeing the microprocessor address and data bus for other operations. Following the initiation of write cycle, the device will go to a busy state and automatically clear and write the latched data using an internal control timer. To determine when a write cycle is complete, the 28C04A uses Data polling. Data polling allows the user to read the location last written to when the write operation is complete. CMOS design and processing enables this part to be used in systems where reduced power consumption and reliability are required. A complete family of packages is offered to provide the utmost flexibility in applications.

PACKAGE TYPE



BLOCK DIAGRAM



1.0 ELECTRICAL CHARACTERISTICS

1.1 MAXIMUM RATINGS

V_{CC} and input voltages w.r.t. V_{SS} -0.6V to + 6.25V
 Voltage on $\overline{OE}$ w.r.t. V_{SS} -0.6V to +13.5V
 Output Voltage w.r.t. V_{SS} -0.6V to V_{CC}+0.6V
 Storage temperature -65°C to +125°C
 Ambient temp. with power applied -50°C to +95°C

*Notice: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

TABLE 1-1: PIN FUNCTION TABLE

Name	Function
A0 - A8	Address Inputs
$\overline{CE}$	Chip Enable
$\overline{OE}$	Output Enable
$\overline{WE}$	Write Enable
I/O0 - I/O7	Data Inputs/Outputs
V _{CC}	+5V Power Supply
V _{SS}	Ground
NC	No Connect; No Internal Connection
NU	Not Used; No External Connection is Allowed

TABLE 1-2: READ/WRITE OPERATION DC CHARACTERISTICS

V _{CC} = +5V ±10% Commercial (C): T _{amb} = 0°C to +70°C Industrial (I): T _{amb} = -40°C to +85°C						
Parameter	Status	Symbol	Min	Max	Units	Conditions
Input Voltages	Logic '1' Logic '0'	V _{IH} V _{IL}	2.0 -0.1	V _{CC} +1 0.8	V V	
Input Leakage		I _{LI}	-10	10	μA	V _{IN} = -0.1V to V _{CC} +1
Input Capacitance		C _{IN}		10	pF	V _{IN} = 0V; T _{amb} = 25°C; f = 1 MHz
Output Voltages	Logic '1' Logic '0'	V _{OH} V _{OL}	2.4	0.45	V V	I _{OH} = -400 μA I _{OL} = 2.1 mA
Output Leakage		I _{LO}	-10	10	μA	V _{OUT} = -0.1V to V _{CC} + 0.1V
Output Capacitance		C _{OUT}		12	pF	V _{IN} = 0V; T _{AMB} = 25°C; f = 1 MHz
Power Supply Current, Active	TTL input	I _{CC}		30	mA	f = 5 MHz (Note 1) V _{CC} = 5.5V
Power Supply Current, Standby	TTL input TTL input CMOS input	I _{CC} (s)TTL I _{CC} (s)TTL I _{CC} (s)CMOS		2 3 100	mA mA μA	$\overline{CE}$ = V _{IH} (0°C to +70°C) $\overline{CE}$ = V _{IH} (-40°C to +85°C) $\overline{CE}$ = V _{CC} -0.3 to V _{CC} +1

Note 1: AC power supply current above 5 MHz; 1 mA/MHz

TABLE 1-3: READ OPERATION AC CHARACTERISTICS

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AC Testing Waveform: $V_{IH} = 2.4V$; $V_{IL} = 0.45V$; $V_{OH} = 2.0V$; $V_{OL} = 0.8V$
 Output Load: 1 TTL Load + 100 pF
 Input Rise and Fall Times: 20 ns
 Ambient Temperature: Commercial (C): $T_{amb} = 0^{\circ}C$ to $+70^{\circ}C$
 Industrial (I): $T_{amb} = -40^{\circ}C$ to $+85^{\circ}C$

Parameter	Sym	28C04A-15		28C04A-20		28C04A-25		Units	Conditions
		Min	Max	Min	Max	Min	Max		
Address to Output Delay	t_{ACC}		150		200		250	ns	$\overline{OE} = \overline{CE} = V_{IL}$
$\overline{CE}$ to Output Delay	t_{CE}		150		200		250	ns	$\overline{OE} = V_{IL}$
$\overline{OE}$ to Output Delay	t_{OE}		70		80		100	ns	$\overline{CE} = V_{IL}$
$\overline{CE}$ to $\overline{OE}$ High Output Float	t_{OFF}	0	50	0	55	0	70	ns	
Output Hold from Address, $\overline{CE}$ or $\overline{OE}$, whichever occurs first	t_{OH}	0		0		0		ns	

FIGURE 1-1: READ WAVEFORMS

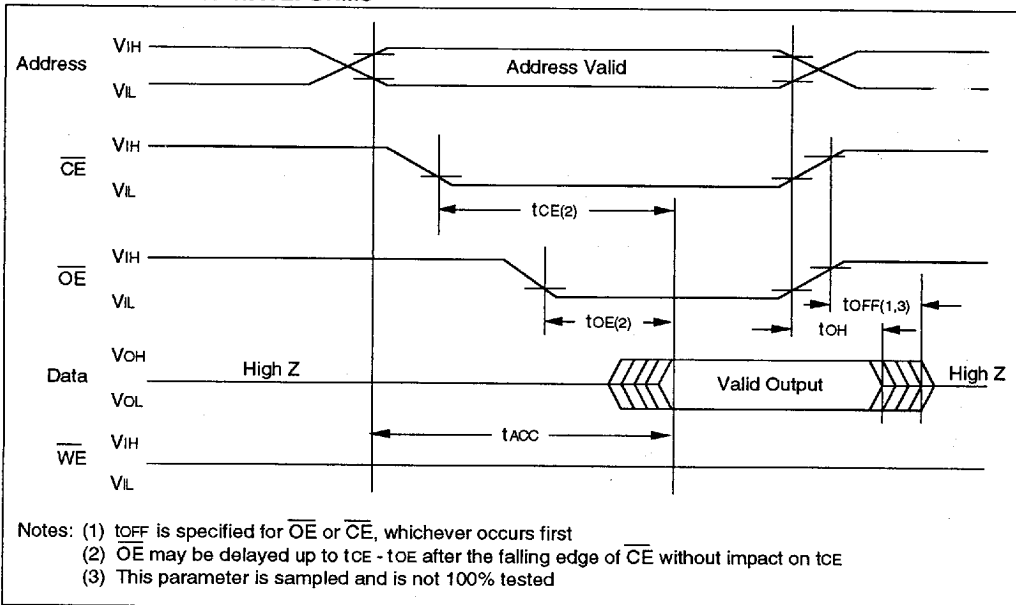


FIGURE 1-2: BYTE WRITE AC CHARACTERISTICS

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AC Testing Waveform:			$V_{IH} = 2.4V$; $V_{IL} = 0.45V$; $V_{OH} = 2.0V$; $V_{OL} = 0.8V$		
Output Load:			1 TTL Load + 100 pF		
Input Rise/Fall Times:			20 nsec		
Ambient Temperature:			Commercial (C): $T_{amb} = 0^{\circ}C$ to $70^{\circ}C$ Industrial (I): $T_{amb} = -40^{\circ}C$ to $85^{\circ}C$		
Parameter	Symbol	Min	Max	Units	Remarks
Address Set-Up Time	t_{AS}	10		ns	
Address Hold Time	t_{AH}	50		ns	
Data Set-Up Time	t_{DS}	50		ns	
Data Hold Time	t_{DH}	10		ns	
Write Pulse Width	t_{WPL}	100		ns	Note 1
Write Pulse High Time	t_{WPH}	50		ns	
$\overline{OE}$ Hold Time	t_{OEH}	10		ns	
$\overline{OE}$ Set-Up Time	t_{OES}	10		ns	
Data Valid Time	t_{DV}		1000	ns	Note 2
Write Cycle Time (28C04A)	t_{WC}		1	ms	0.5 ms typical
Write Cycle Time (28C04AF)	t_{WC}		200	μs	100 μs typical

Note 1: A write cycle can be initiated by $\overline{CE}$ or $\overline{WE}$ going low, whichever occurs last. The data is latched on the positive edge of $\overline{CE}$ or $\overline{WE}$, whichever occurs first.

Note 2: Data must be valid within 1000ns max. after a write cycle is initiated and must be stable at least until t_{DH} after the positive edge of $\overline{WE}$ or $\overline{CE}$, whichever occurs first.

FIGURE 1-3: PROGRAMMING WAVEFORMS

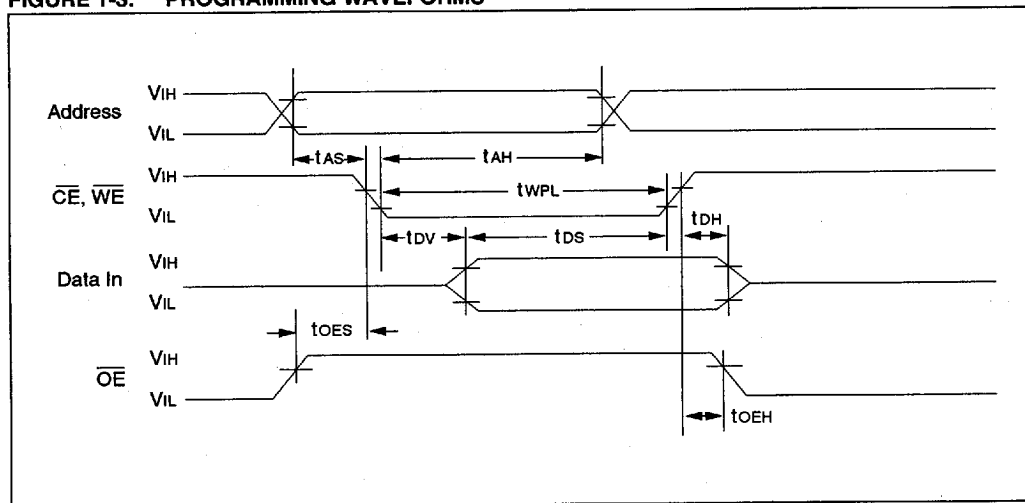


FIGURE 1-4: DATA POLLING WAVEFORMS

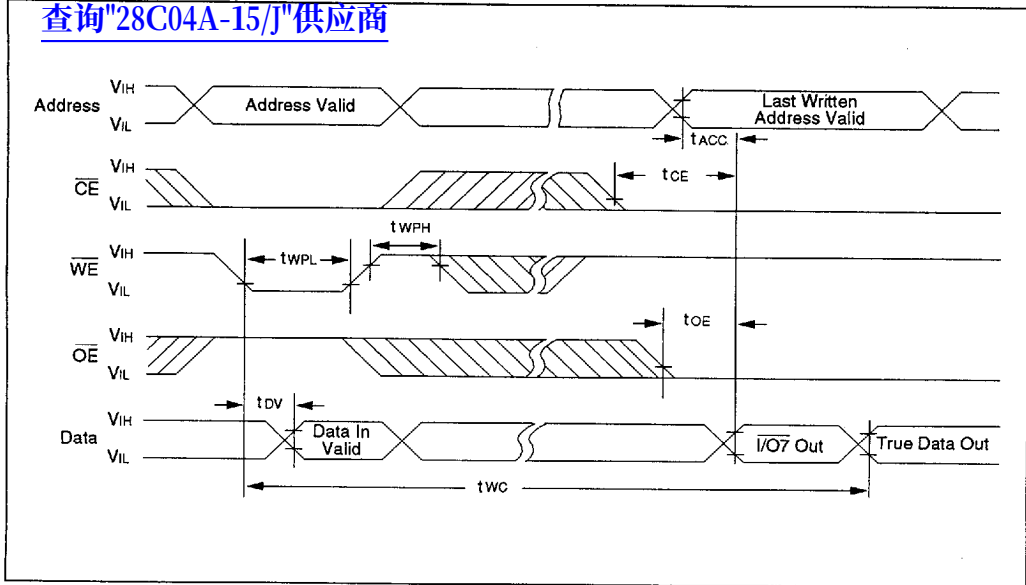
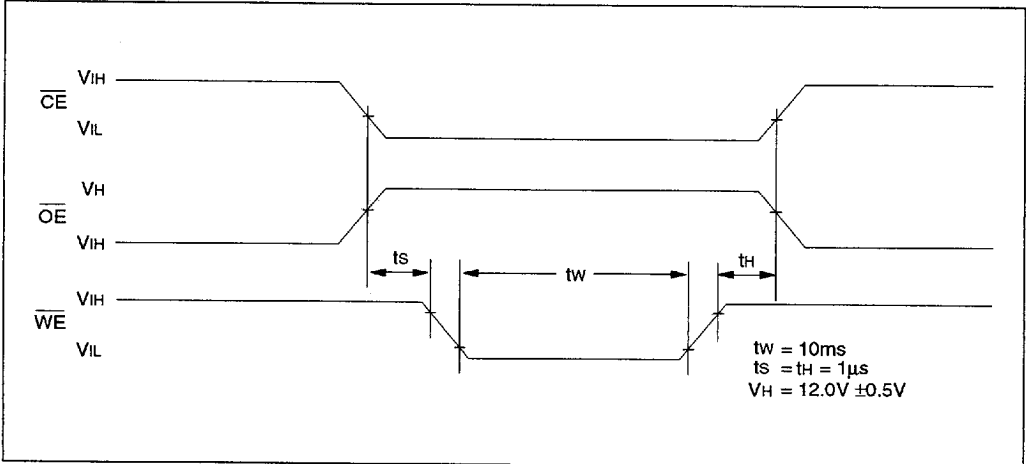
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FIGURE 1-5: CHIP CLEAR WAVEFORMS



2.0 DEVICE OPERATION

The Microchip Technology Inc. 28C04A has four basic modes of operation—read, standby, write inhibit, and byte write—as outlined in the following table.

Operation Mode	$\overline{CE}$	$\overline{IE}$	$\overline{WE}$	I/O
Read	L	L	H	DOUT
Standby	H	X	X	High Z
Write Inhibit	H	X	X	High Z
Write Inhibit	X	L	X	High Z
Write Inhibit	X	X	H	High Z
Byte Write	L	H	L	DIN
Byte Clear	Automatic Before Each "Write"			

X = Any TTL level.

2.1 Read Mode

The 28C04A has two control functions, both of which must be logically satisfied in order to obtain data at the outputs. Chip enable ($\overline{CE}$) is the power control and should be used for device selection. Output Enable ($\overline{OE}$) is the output control and is used to gate data to the output pins independent of device selection. Assuming that addresses are stable, address access time (t_{ACC}) is equal to the delay from $\overline{CE}$ to output (t_{CE}). Data is available at the output t_{OE} after the falling edge of $\overline{OE}$, assuming that $\overline{CE}$ has been low and addresses have been stable for at least $t_{ACC}-t_{OE}$.

2.2 Standby Mode

The 28C04A is placed in the standby mode by applying a high signal to the $\overline{CE}$ input. When in the standby mode, the outputs are in a high impedance state, independent of the $\overline{OE}$ input.

2.3 Data Protection

In order to ensure data integrity, especially during critical power-up and power-down transitions, the following enhanced data protection circuits are incorporated:

First, an internal Vcc detect (3.3 volts typical) will inhibit the initiation of non-volatile programming operation when Vcc is less than the Vcc detect circuit trip.

Second, there is a $\overline{WE}$ filtering circuit that prevents $\overline{WE}$ pulses of less than 10 ns duration from initiating a write cycle.

Third, holding $\overline{WE}$ or $\overline{CE}$ high or $\overline{OE}$ low, inhibits a write cycle during power-on and power-off (Vcc).

2.4 Write Mode

The 28C04A has a write cycle similar to that of a Static RAM. The write cycle is completely self-timed and initiated by a low going pulse on the $\overline{WE}$ pin. On the falling edge of $\overline{WE}$, the address information is latched. On rising edge, the data and the control pins ($\overline{CE}$ and $\overline{OE}$) are latched.

2.5 Data Polling

The 28C04A features Data polling to signal the completion of a byte write cycle. During a write cycle, an attempted read of the last byte written results in the data complement of I/O7 (I/O0 to I/O6 are indeterminate). After completion of the write cycle, true data is available. Data polling allows a simple read/compare operation to determine the status of the chip eliminating the need for external hardware.

2.6 Chip Clear

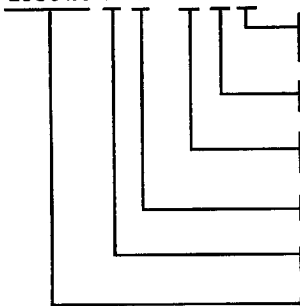
All data may be cleared to 1's in a chip clear cycle by raising $\overline{OE}$ to 12 volts and bringing the $\overline{WE}$ and $\overline{CE}$ low. This procedure clears all data.

28C04A

28C04A Product Identification System

To order or to obtain information, e.g. on pricing or delivery, please use the listed part numbers, and refer to the factory or the listed sales offices.

28C04A F T - 15 I/P



Package:	J = CERDIP L = Plastic Leaded Chip Carrier (PLCC) P = Plastic DIP
Temperature Range:	Blank = 0°C to +70°C I = -40°C to +85°C
Access Time:	15 150 ns 20 200 ns 25 250 ns
Shipping:	Blank Tube T Tape and Reel "L" only.
Option:	- = twc = 1ms F = twc = 200 µs
Device:	28C04A 512 x 8 CMOS EEPROM

Sales and Support

Products supported by a preliminary Data Sheet may possibly have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

1. Your local Microchip sales office
2. The Microchip Corporate Literature Center U.S. FAX: (602) 786-7277
3. The Microchip's Bulletin Board, via your local CompuServe number (CompuServe membership NOT required).

Please specify which device, revision of silicon and Data Sheet (include Literature #) you are using.

For latest version information and upgrade kits for Microchip Development Tools, please call 1-800-755-2345 or 1-602-786-7302.

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